



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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11/27/90  
Snugelc  
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In re application of:

JOSEPH T. EVANS, JR. ET AL.

Serial No.:

582,672

Filed:

September 14, 1990

GROUP 2B

Group:

233

For:

NON-VOLATILE MEMORY CIRCUIT USING  
FERROELECTRIC CAPACITOR STORAGE ELEMENT

Honorable Commissioner of  
Patents and Trademarks  
Washington, D.C. 20231

Dear Sir:

ASSOCIATE POWER OF ATTORNEY

I, Dale B. Nixon, Registration No. 28,454, hereby  
appoint:

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whose address is National Semiconductor Corporation,  
P. O. Box 58090, Santa Clara, California 95052-8090, as  
associate attorneys in the above-identified application for  
Letters Patent, with full power to transact all business in  
the Patent and Trademark Office connected therewith.

Respectfully submitted,

RICHARDS, MEDLOCK & ANDREWS

By Dale B. Nixon  
Dale B. Nixon

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October 9, 1990  
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I hereby certify that this correspondence is being deposited  
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Commissioner of Patents and Trademarks,

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Dale B. Nixon, Reg. No. 28,454

Name of applicant, assignee, or  
Registered Representative

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Signature

10/9/90

Date of Signature